

Title (en)

SUPPORT SUBSTRATE FOR RADIOISOTOPE PRODUCTION, TARGET PLATE FOR RADIOISOTOPE PRODUCTION, AND PRODUCTION METHOD FOR SUPPORT SUBSTRATE

Title (de)

TRÄGERSUBSTRAT ZUR RADIOISOTOPHERSTELLUNG, ZIELPLATTE ZUR RADIOISOTOPHERSTELLUNG UND HERSTELLUNGSVERFAHREN FÜR TRÄGERSUBSTRAT

Title (fr)

SUBSTRAT DE SUPPORT POUR LA PRODUCTION DE RADIO-ISOTOPES, PLAQUE CIBLE POUR LA PRODUCTION DE RADIO-ISOTOPES, ET PROCÉDÉ DE PRODUCTION D'UN SUBSTRAT DE SUPPORT

Publication

**EP 3447774 A1 20190227 (EN)**

Application

**EP 17786034 A 20170420**

Priority

- JP 2016085301 A 20160421
- JP 2017015932 W 20170420

Abstract (en)

Provided is a target plate for radioisotope production that has sufficient durability and sufficient heat resistance for use in radioisotope production and that is capable of reducing the extent of radioactivation. In a target plate (10) for radioisotope production, a support substrate (2), which supports a target (1), includes a graphite film(s). The thermal conductivity in a surface direction of the graphite film(s) is 1200 W/(m·K) or greater, and the thickness of the graphite film(s) is 0.05 µm or greater and 100 µm or less.

IPC 8 full level

**G21K 5/08** (2006.01); **C01B 32/205** (2017.01); **C01B 32/21** (2017.01); **G21G 1/10** (2006.01); **G21G 4/08** (2006.01)

CPC (source: EP US)

**B32B 9/007** (2013.01 - US); **B32B 15/04** (2013.01 - US); **C01B 32/205** (2017.07 - EP US); **C01B 32/21** (2017.07 - US);  
**G21G 1/10** (2013.01 - EP US); **G21G 4/08** (2013.01 - US); **G21K 5/08** (2013.01 - US); **H05H 6/00** (2013.01 - EP); **C01P 2006/10** (2013.01 - US);  
**C01P 2006/32** (2013.01 - US); **C01P 2006/40** (2013.01 - US); **H05H 6/00** (2013.01 - US); **H05H 2277/116** (2013.01 - EP)

Designated contracting state (EPC)

AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO PL PT RO RS SE SI SK SM TR

Designated extension state (EPC)

BA ME

DOCDB simple family (publication)

**EP 3447774 A1 20190227; EP 3447774 A4 20190508; EP 3447774 B1 20200527;** CN 108780672 A 20181109; CN 108780672 B 20220301;  
JP 6609041 B2 20191120; JP WO2017183697 A1 20190110; US 11239003 B2 20220201; US 2019051426 A1 20190214;  
WO 2017183697 A1 20171026

DOCDB simple family (application)

**EP 17786034 A 20170420;** CN 201780013388 A 20170420; JP 2017015932 W 20170420; JP 2018513215 A 20170420;  
US 201716077377 A 20170420